# Power LDMOS transistor Rev. 5 — 7 August 2024

**AMPLEON** 

Product data sheet

### **Product profile** 1.

### 1.1 General description

Based on Advanced Rugged Technology (ART), this 2000 W LDMOS RF power transistor has been designed to cover a wide range of applications for ISM, broadcast and communications. The unmatched transistor has a frequency range of 1 MHz to 450 MHz.

Table 1. **Application information** 

Test signal	f	V <sub>DS</sub>	PL	Gp	ηD
	(MHz)	(V)	(W)	(dB)	(%)
CW	41	65	1600	28.8	79.4
CW pulsed [1][2]	60	55	1250	24.7	85.8
CW pulsed [1][2]	60	65	1690	25.1	83.3
CW pulsed [1][2]	64	65	1785	25.7	84.7
CW [3]	87.5 to 108	60	1730	25.8	85.1

<sup>[1]</sup>  $t_p = 100 \ \mu s; \ \delta = 10 \%.$ 

### 1.2 Features and benefits

- High breakdown voltage enables class E operation up to V<sub>DS</sub> = 53 V
- Qualified up to a maximum of V<sub>DS</sub> = 65 V
- Characterized from 30 V to 65 V to support a wide range of applications
- Integrated dual sided ESD protection enables class C operation and complete switch off of the transistor
- Excellent ruggedness with no device degradation
- High efficiency
- Excellent thermal stability
- Designed for broadband operation
- For RoHS compliance see the product details on the Ampleon website

<sup>[2]</sup> Performance at 3 dB gain compression level.

<sup>[3]</sup> Center band performance numbers across the indicated frequency range.

### 1.3 Applications

- Industrial, scientific and medical applications
  - Plasma generators
  - ◆ MRI systems
  - ◆ Particle accelerators
- Broadcast
  - ◆ FM radio
  - ◆ VHF TV
- Communications
  - Non cellular communications
  - UHF radar

## 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
ART2	2K0PE (OMP-1230-4F-1)		
1	gate1		,
2	gate2	4 3	
3	drain2		1_1
4	drain1		5
5	source [1]	1 2	3 amp01358
ART2	2K0PEG (OMP-1230-4G-1	)	
1	gate1		
2	gate2	4 3	<u></u>
3	drain2		1_
4	drain1	<u> </u>	5
5	source [1]	1 2	3 amp01358

[1] Connected to flange.

## 3. Ordering information

Table 3. Ordering information

	3			
Package name	Orderable part number	12NC	Packing description	Min. orderable quantity (pieces)
OMP-1230-4F-1	ART2K0PEZ	9349 606 96517	Tray; 20-fold; dry pack	60
	ART2K0PEY	9349 606 96518	TR13; 100-fold; 56 mm; dry pack	100
OMP-1230-4G-1	ART2K0PEGZ	9349 606 97517	Tray; 20-fold; dry pack	60
	ART2K0PEGY	9349 606 97518	TR13; 100-fold; 56 mm; dry pack	100

ART2K0PE\_ART2K0PEG

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### **Limiting values** 4.

Table 4. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DS}$	drain-source voltage	[1]	-	200	V
$V_{GS}$	gate-source voltage		<b>-9</b>	+13	V
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature	[2]	-	225	°C

<sup>[1]</sup> Specified over lifetime at maximum operating temperature.

### **Thermal characteristics**

Table 5. Thermal characteristics

According to standard MIL-STD-883E.

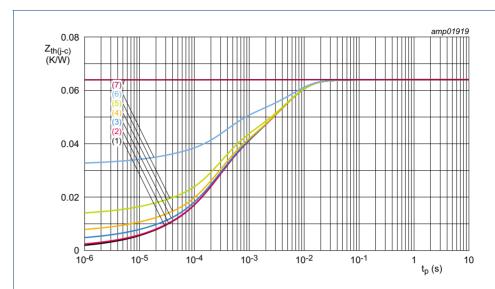
Symbol	Parameter	Conditions	Тур	Unit
R <sub>th(j-c)</sub>	thermal resistance from junction to case	T <sub>j</sub> = 95 °C, measured under RF condition [1][2]	0.064	K/W

Refer to application note AN221014 on the Ampleon website.

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<sup>[2]</sup> Continuous use at maximum temperature will affect the reliability.

See Figure 1.



- (1)  $\delta$  = 0.1 % (single push)
- (2)  $\delta = 1 \%$
- (3)  $\delta = 5 \%$
- (4)  $\delta = 10 \%$
- (5)  $\delta = 20 \%$
- (6)  $\delta = 50 \%$
- (7)  $\delta$  = 100 % (steady state)

Fig 1. Transient thermal impedance from junction to case as a function of pulse duration

### 6. Characteristics

### Table 6. DC characteristics

 $T_i$  = 25 °C; per section unless otherwise specified.

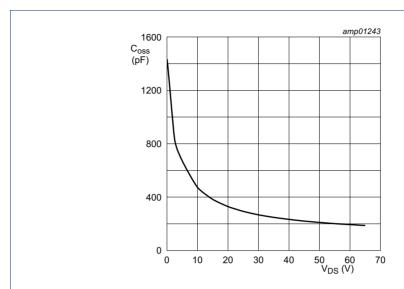
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 5.5 \text{ mA}$	203	208	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 20 \text{ V}; I_D = 550 \text{ mA}$	1.6	2.1	2.6	V
I <sub>DSS</sub>	drain leakage current	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 65 V	-	-	2.8	μА
I <sub>DSX</sub>	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 20 \text{ V}$	-	76	-	Α
I <sub>GSS</sub>	gate leakage current	V <sub>GS</sub> = 11 V; V <sub>DS</sub> = 0 V	-	-	280	nA
R <sub>DS(on)</sub>	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 19.25 \text{ A}$	_	0.106	-	Ω

### Table 7. AC characteristics

 $T_i$  = 25 °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>rs</sub>	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 65 \text{ V}; f = 1 \text{ MHz}$	-	3.27	-	pF
C <sub>iss</sub>	input capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 65 V; f = 1 MHz	-	614	-	pF
Coss	output capacitance	V <sub>GS</sub> = 0 V; V <sub>DS</sub> = 65 V; f = 1 MHz	-	187	-	pF

ART2K0PE\_ART2K0PEG



 $V_{GS} = 0 V; f = 1 MHz$ 

Fig 2. Output capacitance as a function of drain-source voltage; typical values per section

#### Table 8. **RF** characteristics

Test signal: pulsed RF;  $t_p$  = 100  $\mu$ s;  $\delta$  = 3 %; f = 108 MHz; RF performance at  $V_{DS}$  = 65 V;  $I_{Dq}$  = 50 mA per section;  $T_{case}$  = 25 °C; unless otherwise specified; in a class-AB production test circuit.

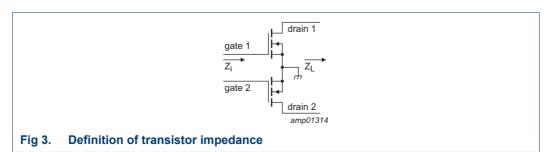
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P <sub>L</sub> = 2000 W	26.5	27.7	-	dB
RLin	input return loss	P <sub>L</sub> = 2000 W	-	<b>–15</b>	-	dB
$\eta_{D}$	drain efficiency	P <sub>L</sub> = 2000 W	68.0	71.7	-	%

#### **Test information** 7.

### 7.1 Ruggedness in class-AB operation

The ART2K0PE and ART2K0PEG are capable of withstanding a load mismatch corresponding to VSWR ≥ 65 : 1 through all phases under the following conditions:  $V_{DS}$  = 65 V;  $I_{Dq}$  = 100 mA per section;  $P_L$  = 2000 W pulsed;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %; f = 108 MHz.

### 7.2 Impedance information



ART2K0PE\_ART2K0PEG

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Table 9. Typical push-pull impedance

Simulated  $Z_i$  and  $Z_L$  device impedance; impedance info at  $V_{DS}$  = 65 V and  $P_L$  = 2000 W.

f	Z <sub>i</sub>	$Z_L$
(MHz)	<b>(Ω)</b>	<b>(</b> Ω <b>)</b>
108	2.4 – j8.7	3.8 + j0.9

### 7.3 Test circuit

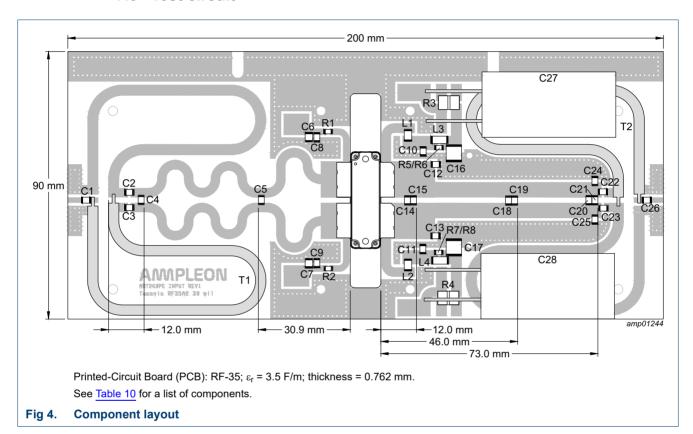


Table 10. List of components

For test circuit see Figure 4.

Component	Description	Value		Remarks
C1, C26	multilayer ceramic chip capacitor	470 pF	[1]	
C2, C3	multilayer ceramic chip capacitor	68 pF	[1]	
C4	multilayer ceramic chip capacitor	43 pF	[1]	
C5	multilayer ceramic chip capacitor	300 pF	[1]	
C6, C7	multilayer ceramic chip capacitor	4.7 μF, 50 V		Murata: GRM32ER71H475KA88L
C8, C9, C10, C11	multilayer ceramic chip capacitor	820 pF	[1]	
C12, C13	multilayer ceramic chip capacitor	180 pF	[1]	
C14, C15	multilayer ceramic chip capacitor	39 pF	[1]	
C16, C17	multilayer ceramic chip capacitor	4.7 μF, 100 V		TDK: C5750X7R2A475KT/A
C18, C19	multilayer ceramic chip capacitor	56 pF	[1]	
C20, C21	multilayer ceramic chip capacitor	51 pF	[1]	

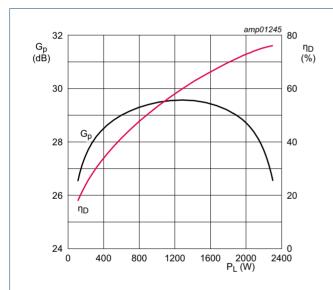
Table 10. List of components ...continued

For test circuit see Figure 4.

Component	Description	Value	Remarks
C22, C23	multilayer ceramic chip capacitor	120 pF [1]	
C24, C25	multilayer ceramic chip capacitor	20 pF [1]	
C27, C28	electrolytic capacitor	2200 μF, 100 V	
L1, L2	air inductor	47 nH	Coilcraft: 1515SQ-47N
L3, L4	air inductor	82 nH	Coilcraft: 1515SQ-82N
R1, R2	resistor	4.7 kΩ	SMD 1206
R3, R4	resistor	0.01 Ω	Vishay: WSHP2818
R5, R6, R7, R8	resistor	9.1 Ω	SMD 1206
T1, T2	semi rigid coax	50 Ω, 160 mm	EZ141-AL-TP/M17

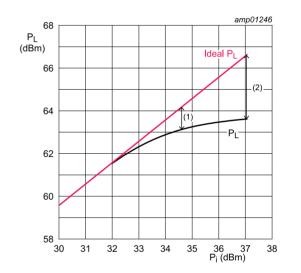
<sup>[1]</sup> American Technical Ceramics type 100B or capacitor of same quality.

### 7.4 Graphical data



 $V_{DS}$  = 65 V;  $I_{Dq}$  = 100 mA per section; f = 108 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %.

Fig 5. Power gain and drain efficiency as function of output power; typical values

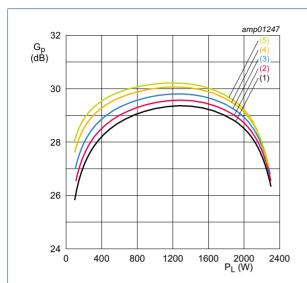


 $V_{DS}$  = 65 V;  $I_{Dq}$  = 100 mA per section; f = 108 MHz;  $t_{D}$  = 100  $\mu$ s;  $\delta$  = 10 %.

- (1)  $P_{L(1dB)} = 63.20 \text{ dBm } (2045 \text{ W})$
- (2)  $P_{L(3dB)} = 63.71 \text{ dBm } (2300 \text{ W})$

Fig 6. Output power as a function of input power; typical values

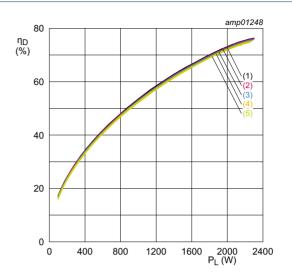
**Power LDMOS transistor** 



 $V_{DS}$  = 65 V; f = 108 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %.

- (1)  $I_{Dq} = 50 \text{ mA per section}$
- (2)  $I_{Dq} = 100 \text{ mA per section}$
- (3)  $I_{Dq} = 200 \text{ mA per section}$
- (4)  $I_{Dq} = 400 \text{ mA per section}$
- (5)  $I_{Dq} = 600 \text{ mA per section}$

Fig 7. Power gain as a function of output power; typical values

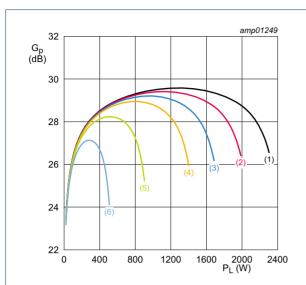


 $V_{DS}$  = 65 V; f = 108 MHz;  $t_p$  = 100  $\mu$ s;  $\delta$  = 10 %.

- (1)  $I_{Dq} = 50 \text{ mA per section}$
- (2)  $I_{Dq} = 100 \text{ mA per section}$
- (3)  $I_{Dq} = 200 \text{ mA per section}$
- (4)  $I_{Dq} = 400 \text{ mA per section}$
- (5)  $I_{Da} = 600 \text{ mA per section}$

Fig 8. Drain efficiency as a function of output power; typical values

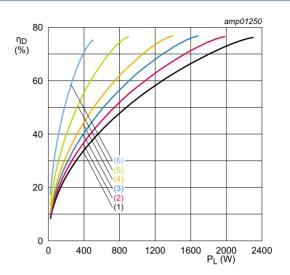
**Power LDMOS transistor** 



 $I_{Dq}$  = 100 mA per section; f = 108 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 10 %.

- (1)  $V_{DS} = 65 \text{ V}$
- (2)  $V_{DS} = 60 \text{ V}$
- (3)  $V_{DS} = 55 V$
- (4)  $V_{DS} = 50 \text{ V}$
- (5)  $V_{DS} = 40 \text{ V}$
- (6)  $V_{DS} = 30 \text{ V}$

Fig 9. Power gain as a function of output power; typical values



 $I_{Dq}$  = 100 mA per section; f = 108 MHz;  $t_p$  = 100  $\mu s;$   $\delta$  = 10 %.

- (1)  $V_{DS} = 65 \text{ V}$
- (2)  $V_{DS} = 60 \text{ V}$
- (3)  $V_{DS} = 55 V$
- (4)  $V_{DS} = 50 V$
- (5)  $V_{DS} = 40 \text{ V}$
- (6)  $V_{DS} = 30 \text{ V}$

Fig 10. Drain efficiency as a function of output power; typical values

### 8. Package outline

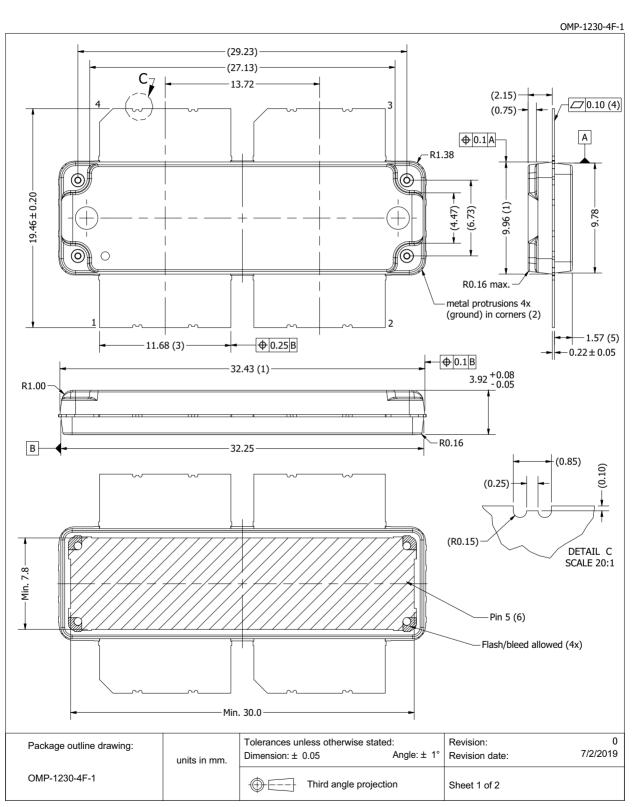
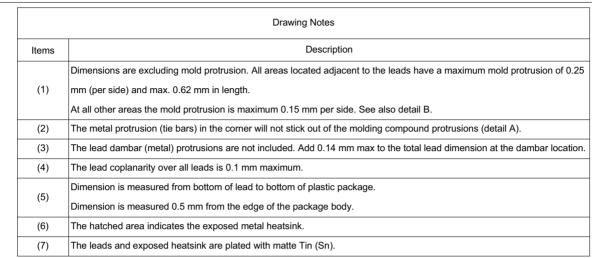


Fig 11. Package outline OMP-1230-4F-1 (sheet 1 of 2)

OMP-1230-4F-1



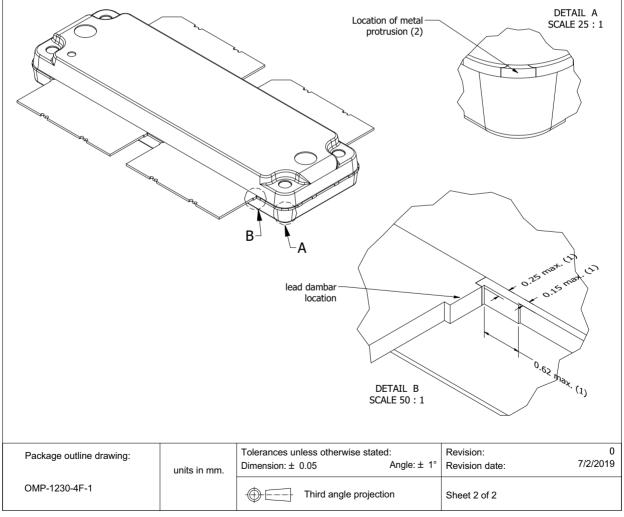


Fig 12. Package outline OMP-1230-4F-1 (sheet 2 of 2)

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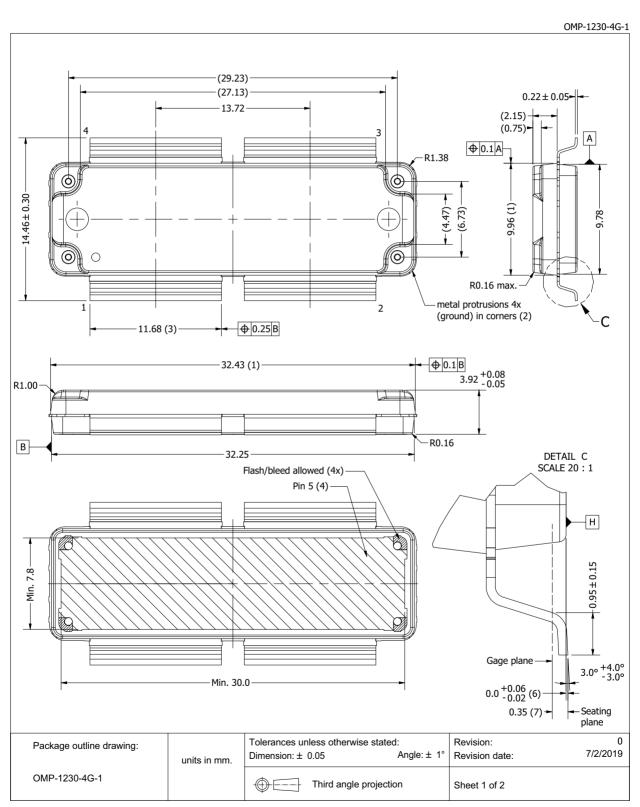
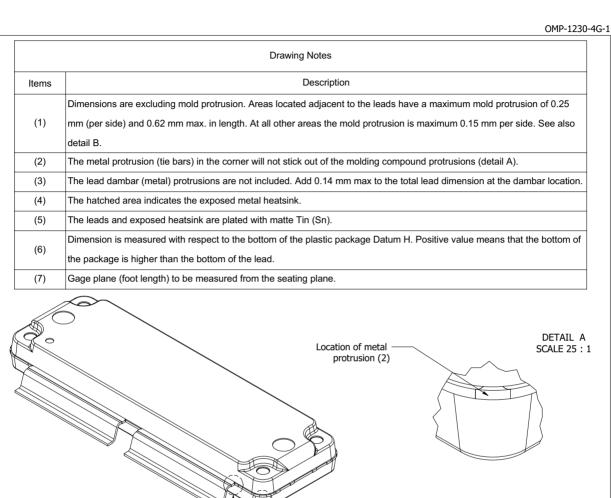


Fig 13. Package outline OMP-1230-4G-1 (sheet 1 of 2)



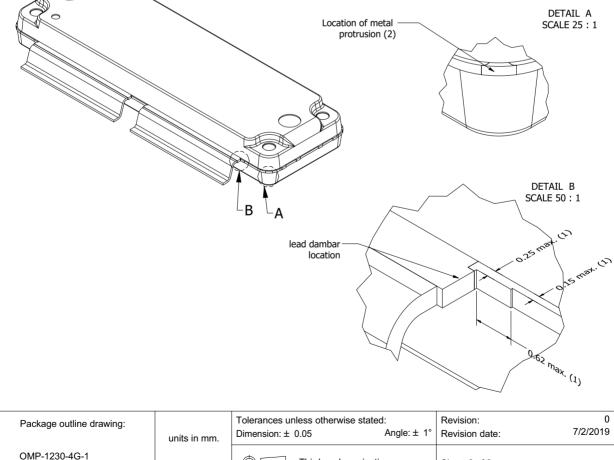


Fig 14. Package outline OMP-1230-4G-1 (sheet 2 of 2)

Third angle projection

Sheet 2 of 2

### 9. Handling information

### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11. ESD sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2

### 10. Abbreviations

Table 12. Abbreviations

Acronym	Description
CW	Continuous Wave
ESD	ElectroStatic Discharge
FM	Frequency Modulation
ISM	Industrial, Scientific and Medical
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MRI	Magnetic Resonance Imaging
RoHS	Restriction of Hazardous Substances
SMD	Surface Mounted Device
UHF	Ultra High Frequency
VHF	Very High Frequency
VSWR	Voltage Standing Wave Ratio

### 11. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
ART2K0PE_ART2K0PEG v.5	20240807	Product data sheet	-	ART2K0PE_ART2K0PEG v.4
Modifications:	• <u>Table 10 on</u>	page 6: changed value	row C8	
ART2K0PE_ART2K0PEG v.4	20230907	Product data sheet	-	ART2K0PE_ART2K0PEG v.3
ART2K0PE_ART2K0PEG v.3	20201019	Product data sheet	-	ART2K0PE v.2
ART2K0PE v.2	20200806	Product data sheet	-	ART2K0PE_ART2K0PEG v.1
ART2K0PE_ART2K0PEG v.1	20200114	Objective data sheet	-	-

### 12. Legal information

### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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## **AMPLEON**

## ART2K0PE; ART2K0PEG

**Power LDMOS transistor** 

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